





## 热特性 THERMAL CHARACTERISTIC

项目 Parameter	符号 Symbol	FHP65R190A	FHA65R190A	FHF65R190A	单位 Unit
结到管壳的热阻 Thermal Resistance, Junction to Case	R <sub>th(j-c)</sub>	0.83	0.6	3.7	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	R <sub>th(j-A)</sub>	62	40	80	°C/W

注释:

- 1: 脉冲宽度由最高结温限制
- 2: L=10mH, I<sub>AS</sub>=9.5A, V<sub>DD</sub>=50V, R<sub>G</sub>=25 Ω, 起始结温 T<sub>J</sub>=25°C
- 3: I<sub>SD</sub> ≤ 20A, di/dt ≤ 200A/μs, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, 起始结温 T<sub>J</sub>=25°C
- 4: 脉冲测试: 脉冲宽度 ≤ 300μs, 占空比≤2%
- 5: 基本与工作温度无关

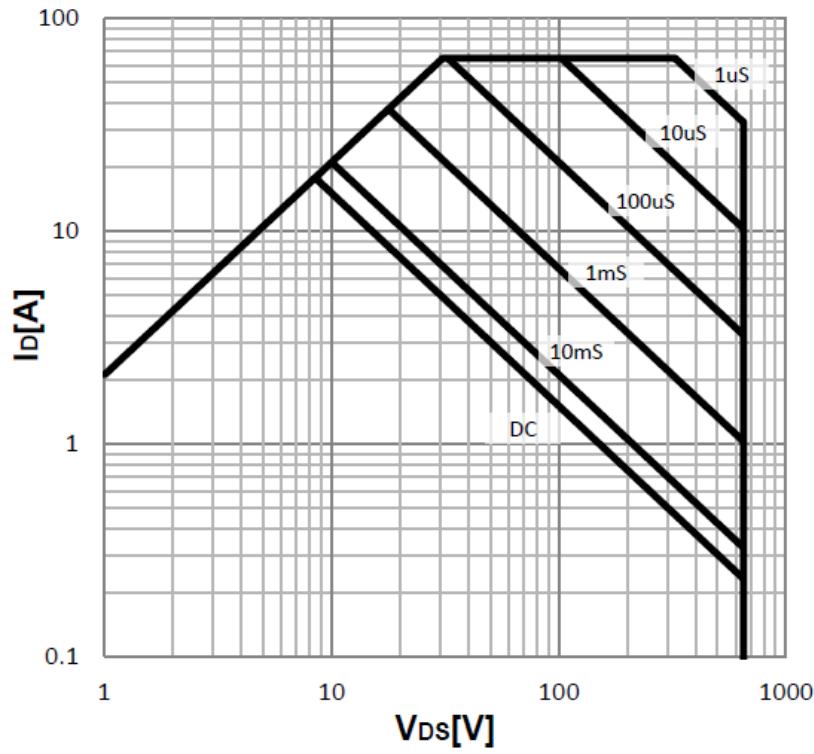
Notes:

- 1: Pulse width limited by maximum junction temperature
- 2: L=10mH, I<sub>AS</sub>=9.5A, V<sub>DD</sub>=50V, R<sub>G</sub>=25 Ω, Starting T<sub>J</sub>=25°C
- 3: I<sub>SD</sub> ≤ 20A, di/dt ≤ 200A/μs, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, Starting T<sub>J</sub>=25°C
- 4: Pulse Test: Pulse Width ≤ 300μs, Duty Cycle≤2%
- 5: Essentially independent of operating temperature

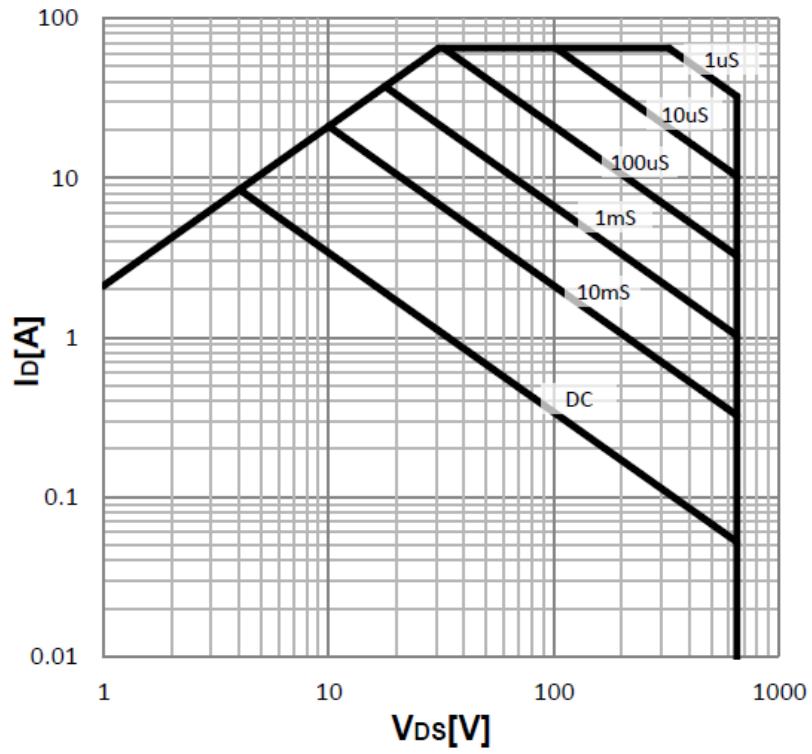
## 典型特性曲线

### ELECTRICAL CHARACTERISTIC CURVE

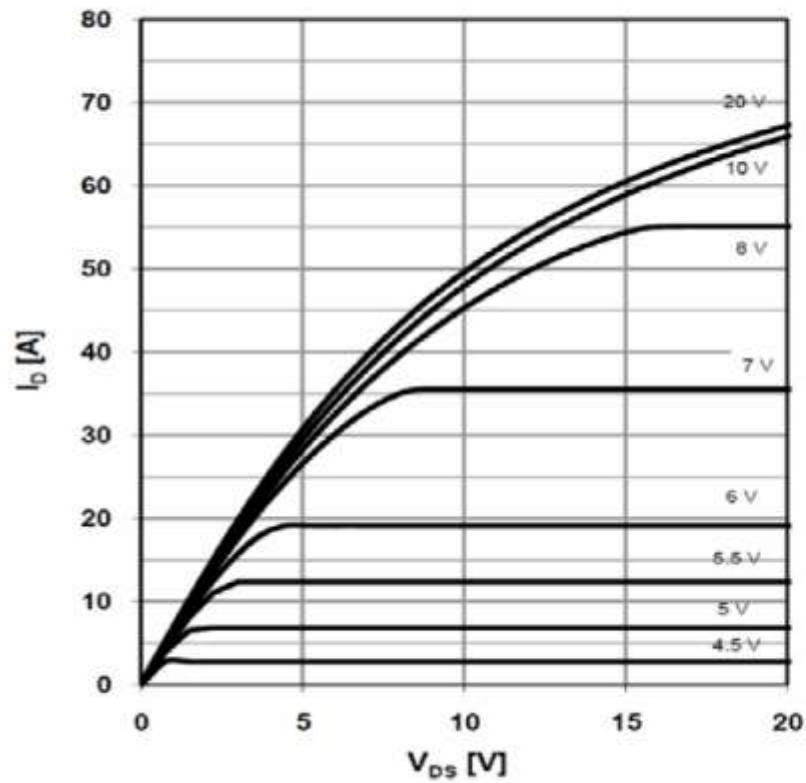
Safe operating area TC=25 °C  
parameter: tp; TO-220, TO-3PN



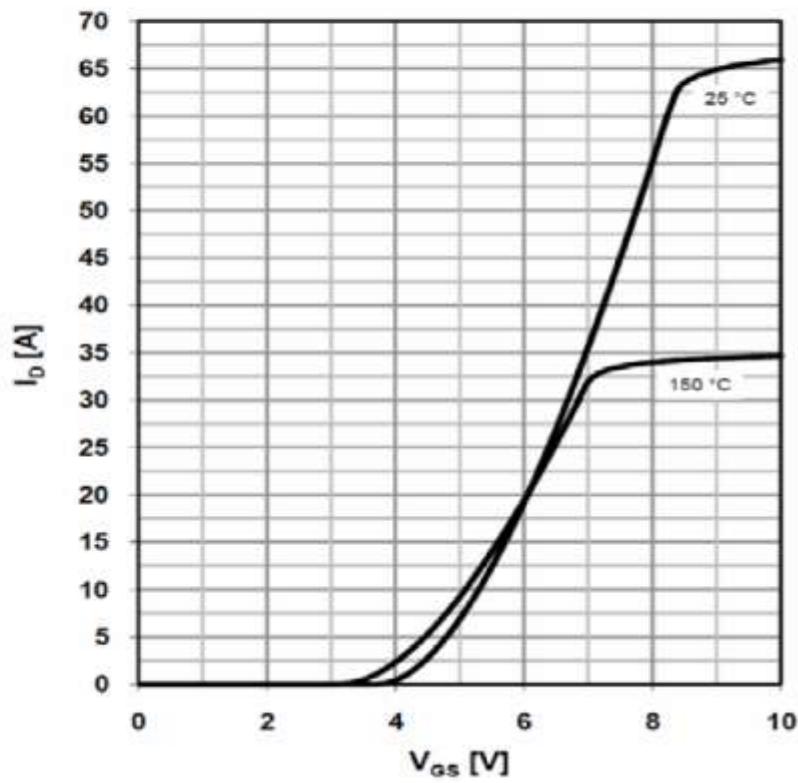
Safe operating area TC=25 °C  
parameter: tp; TO-220FullPAK



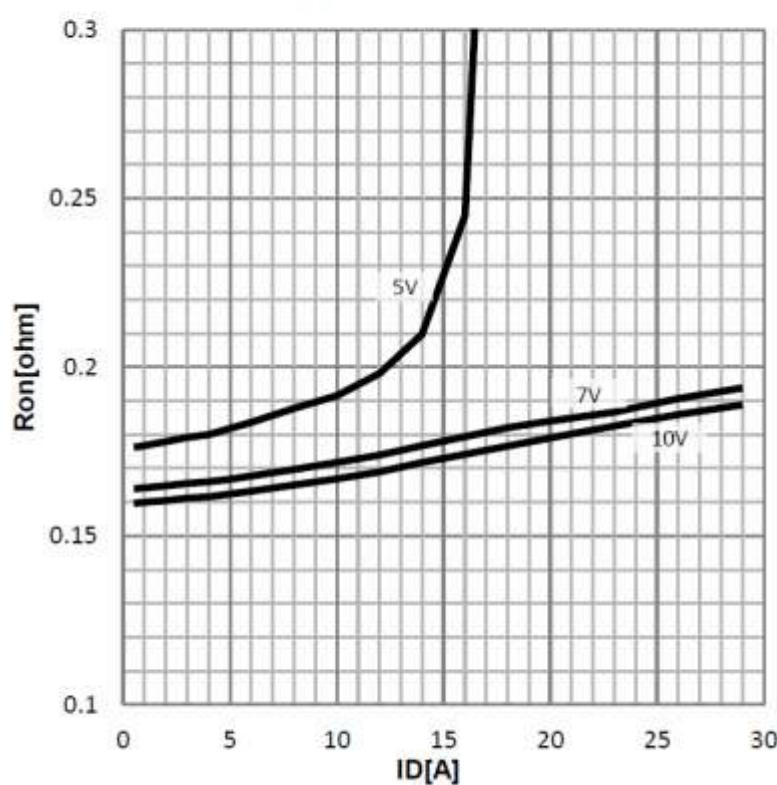
Typ. output characteristics  $T_j=25$  °C  
parameter:  $V_{GS}$



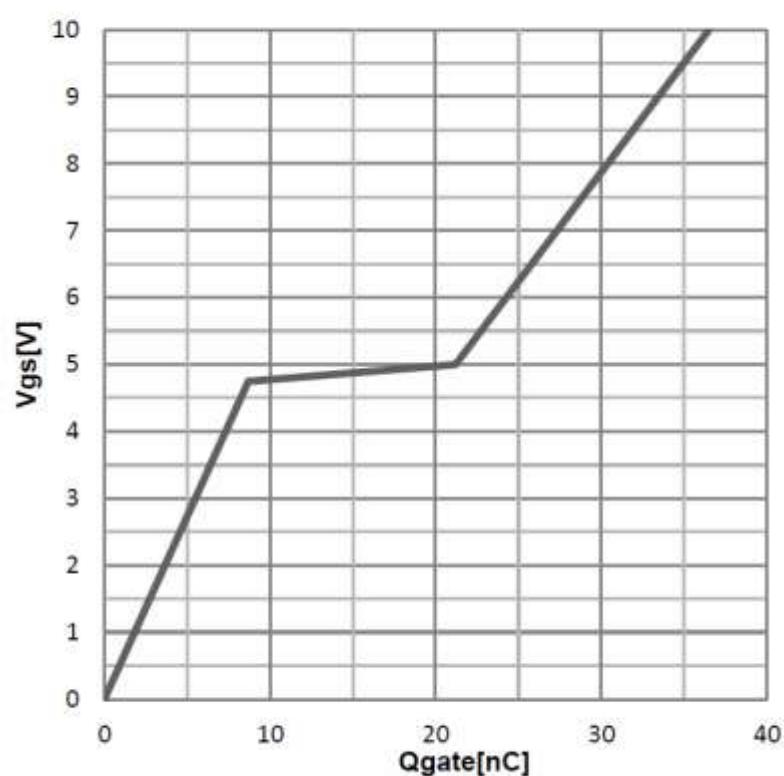
Typ. transfer characteristics



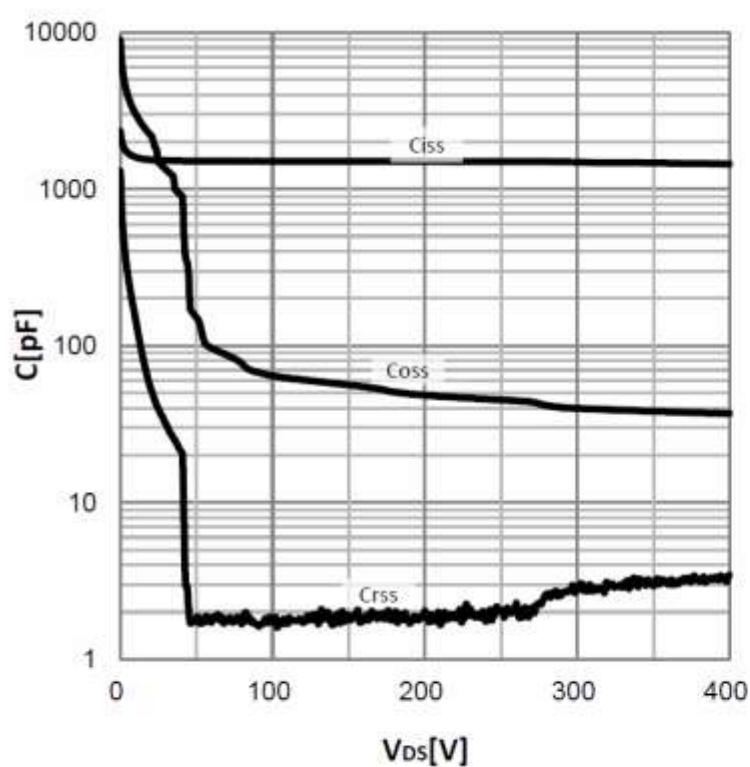
Typ. drain-source on-state resistance  
parameter :  $V_{GS}$



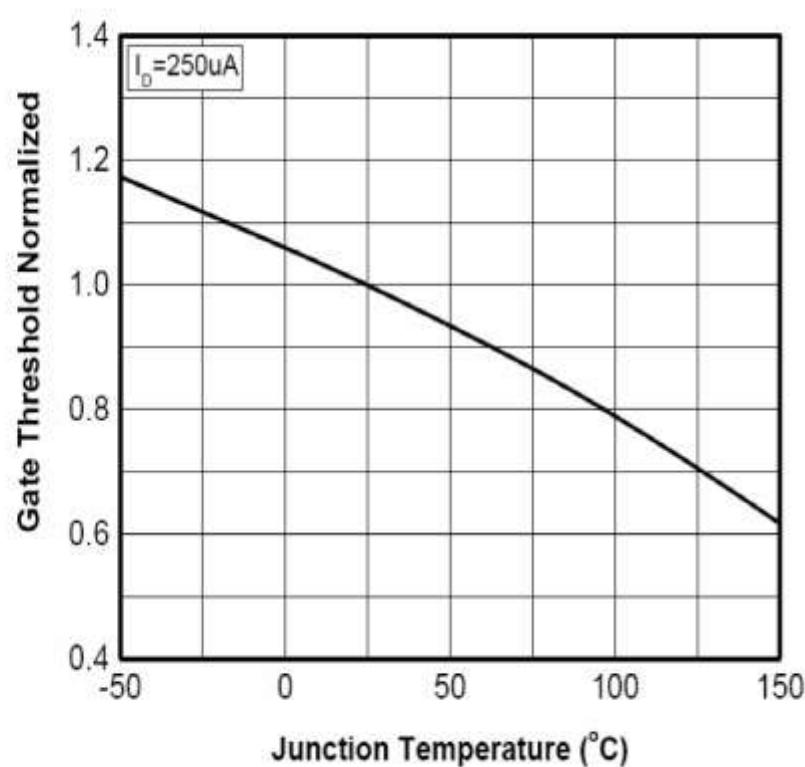
Typ. gate charge characteristics



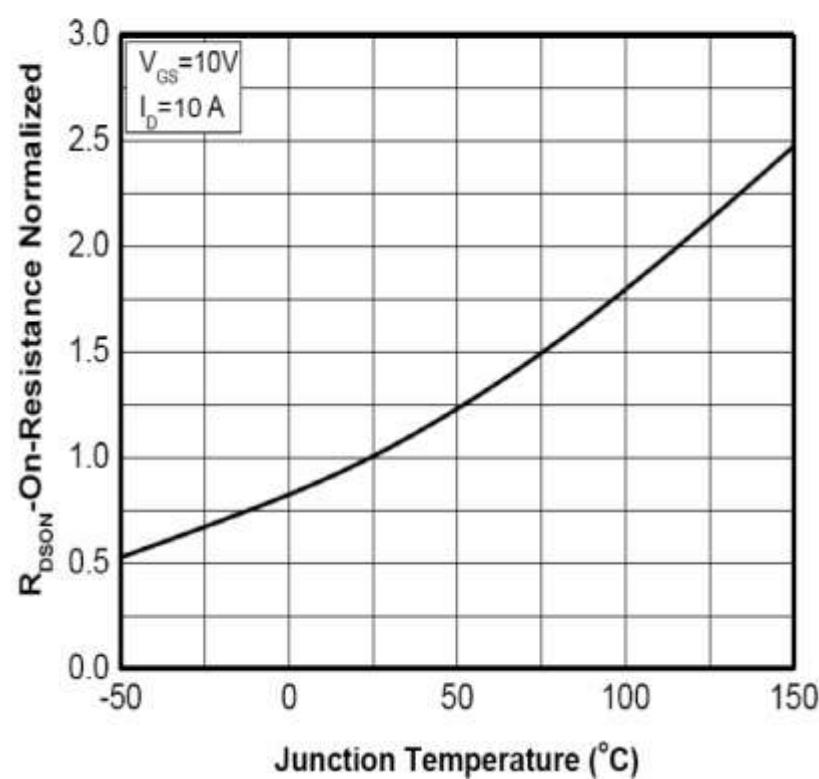
Typ. capacitances



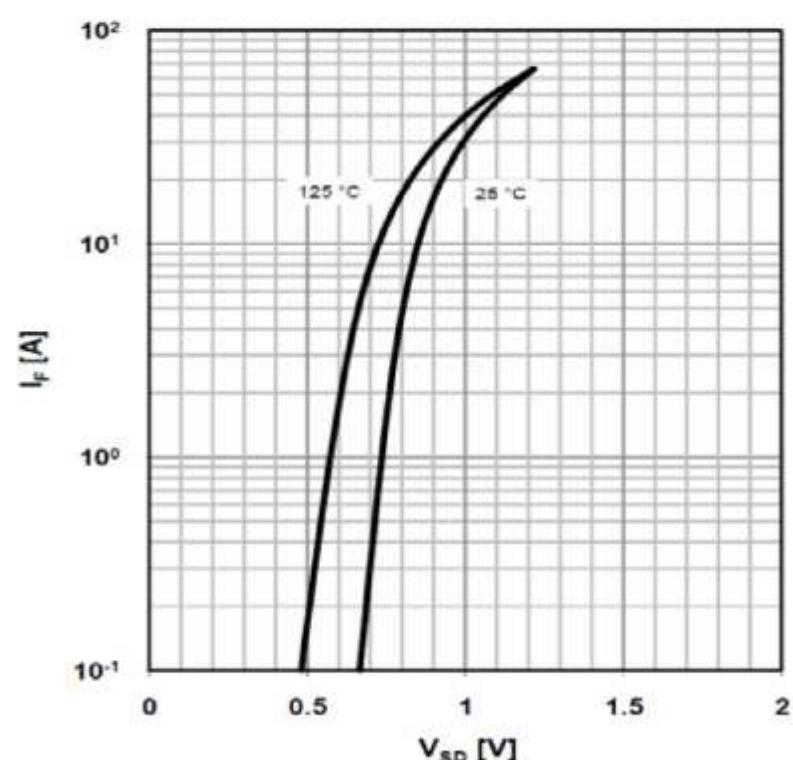
Normalized  $V_{GS(th)}$  characteristics



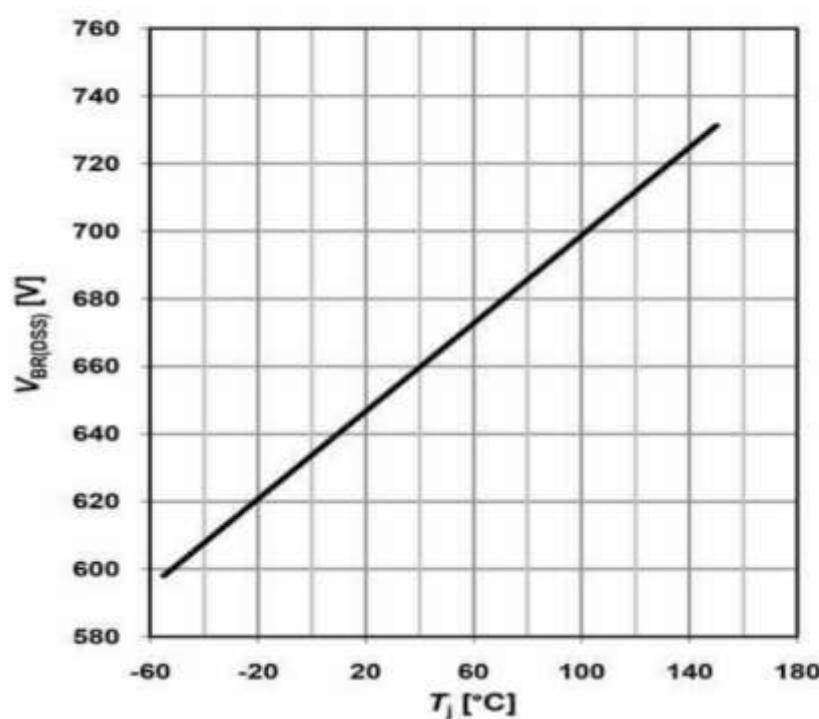
Normalized on resistance vs temperature



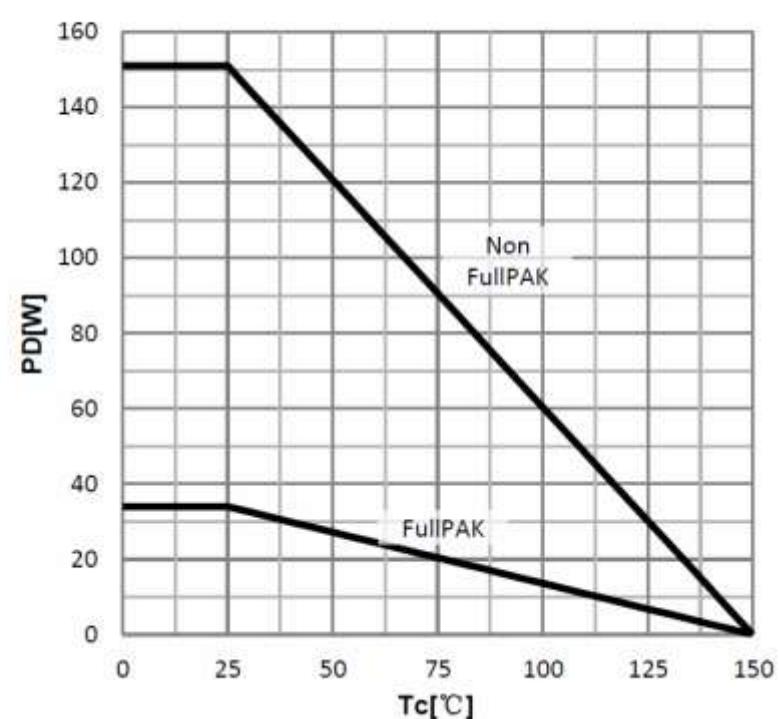
Forward characteristics of reverse diode



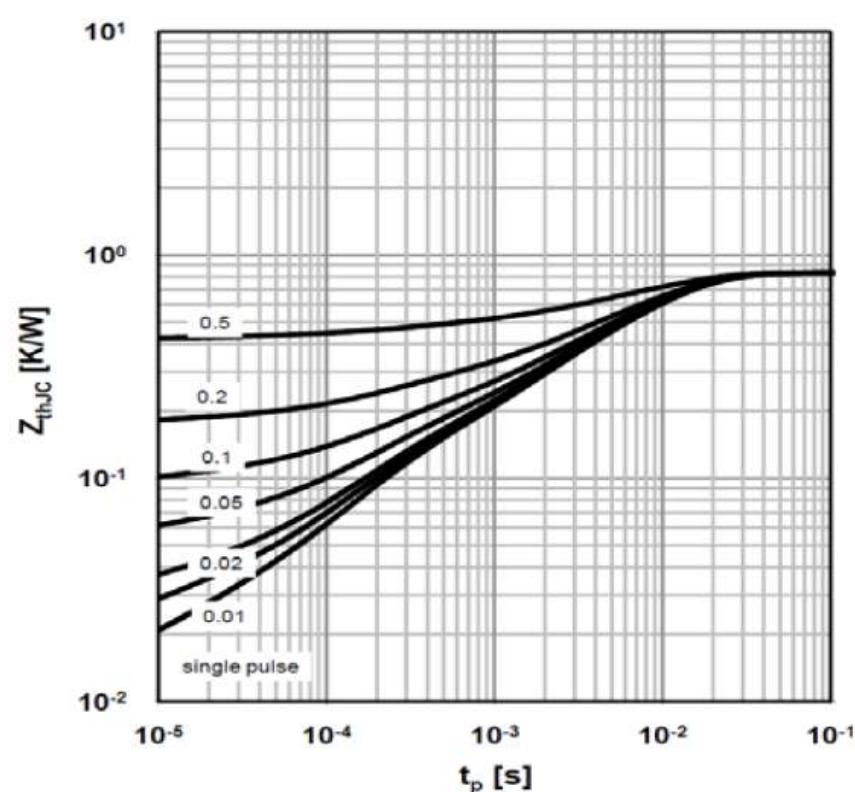
Drain-source breakdown voltage



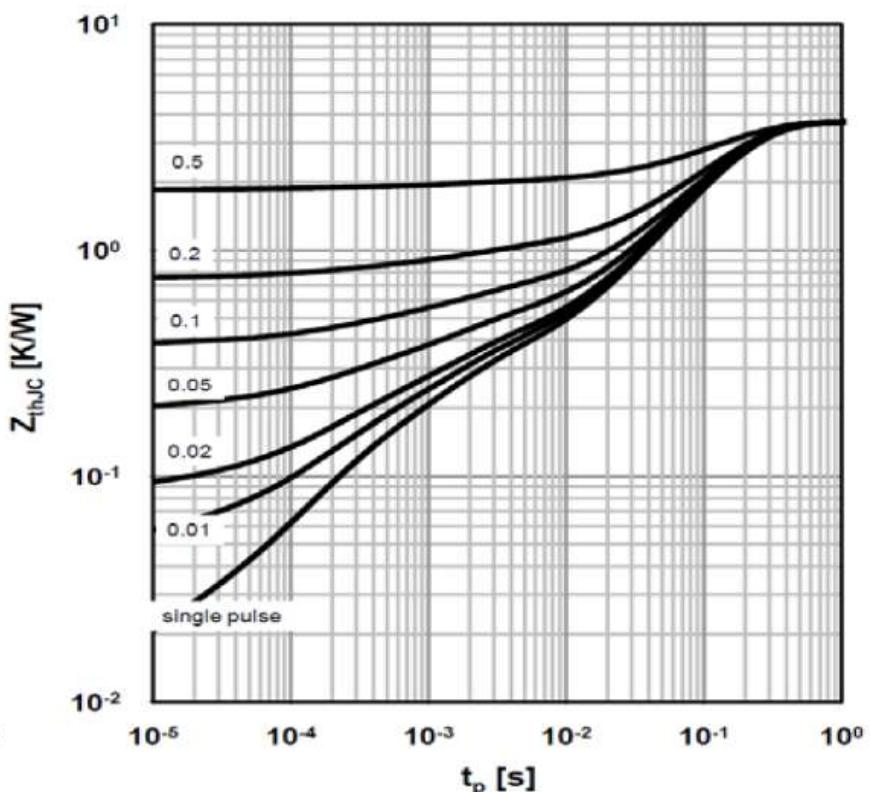
Power dissipation



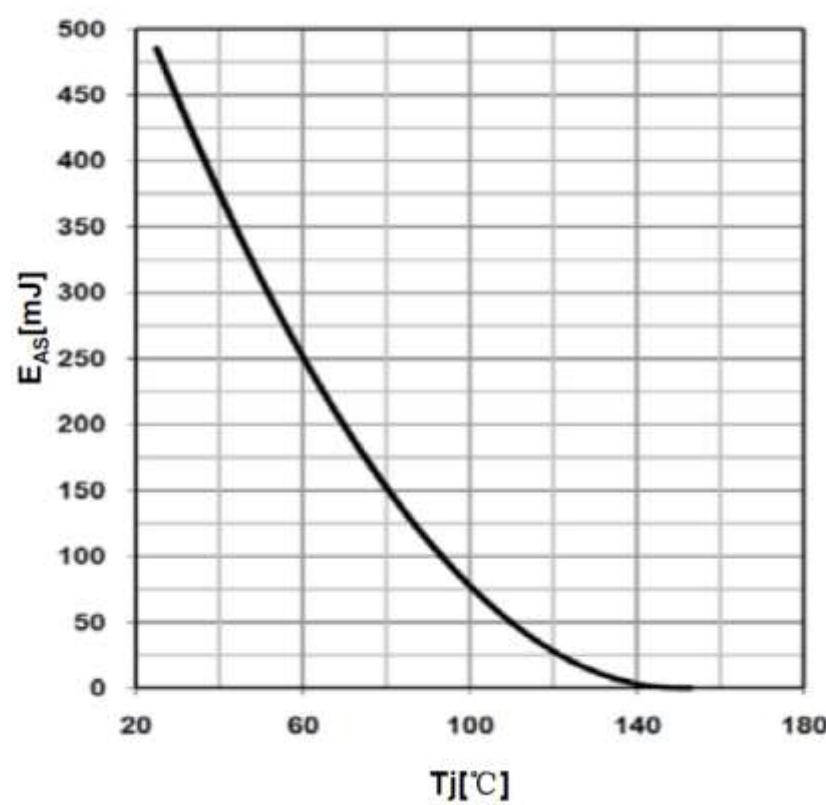
Max. transient thermal impedance  
parameter:  $D = t_p/T$ ; TO-220, TO-3PN



Max. transient thermal impedance  
parameter:  $D = t_p/T$ ; TO-220FullPAK



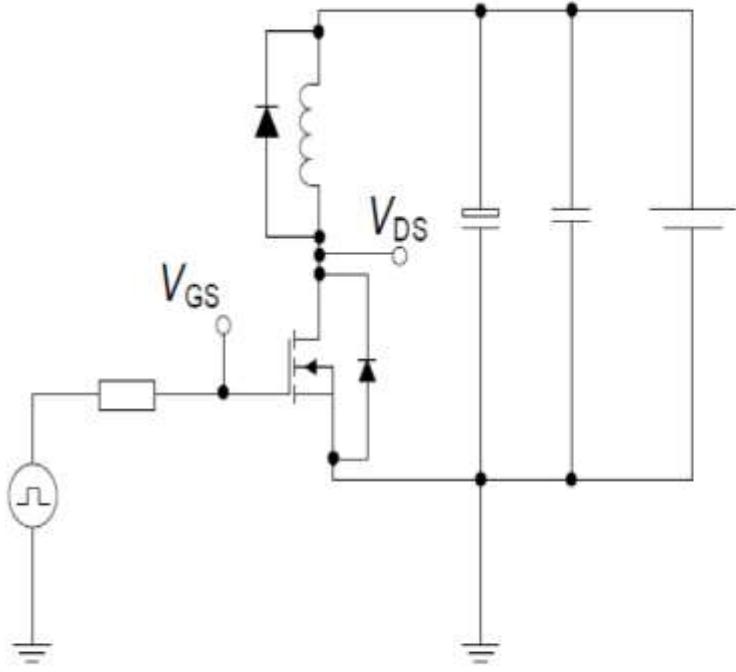
Avalanche energy



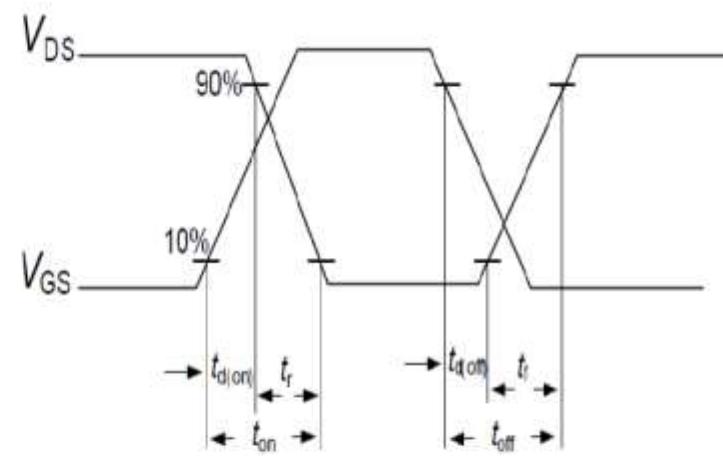
## 测试电路 Test circuits

Switching times test circuit and waveform for inductive load

Switching times test circuit for inductive load

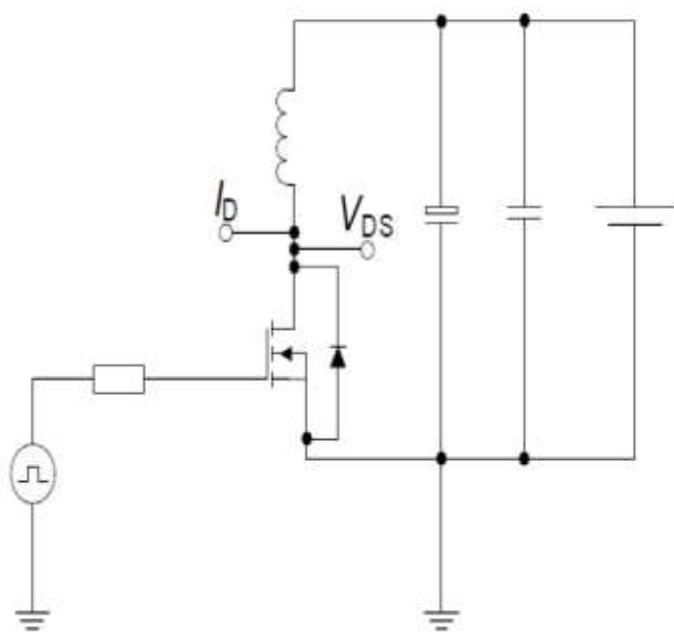


Switching time waveform

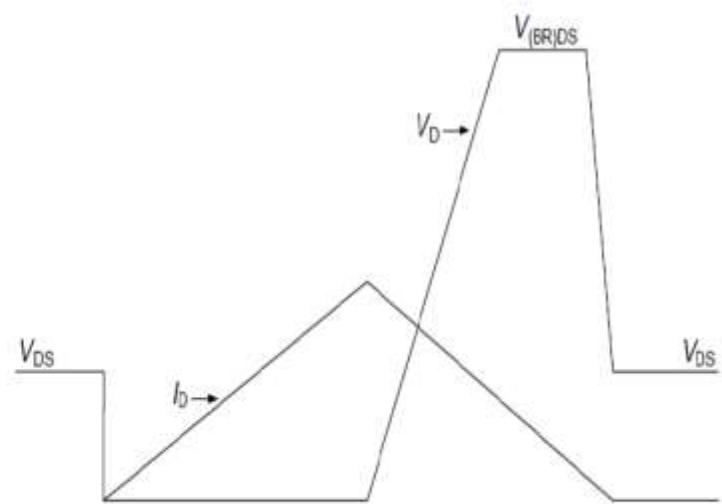


Unclamped inductive load test circuit and waveform

Unclamped inductive load test circuit

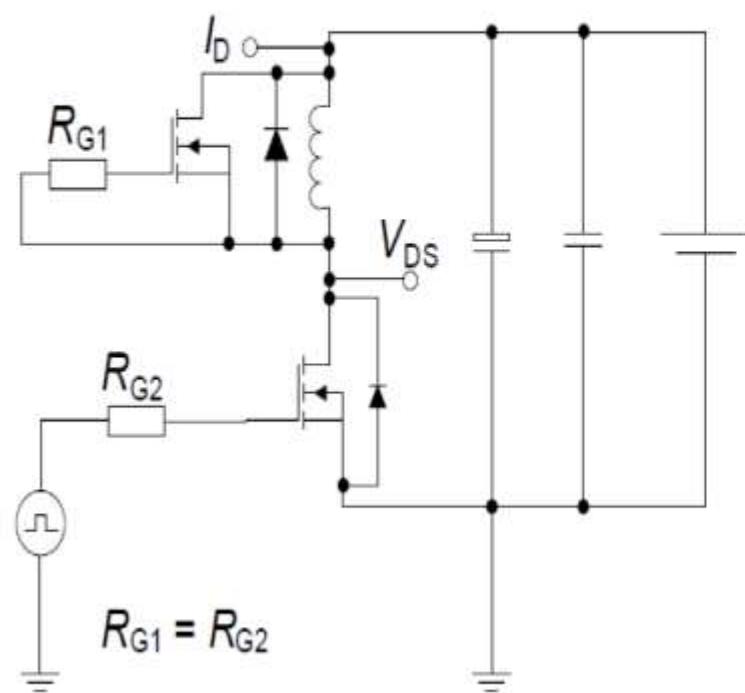


Unclamped inductive load waveform

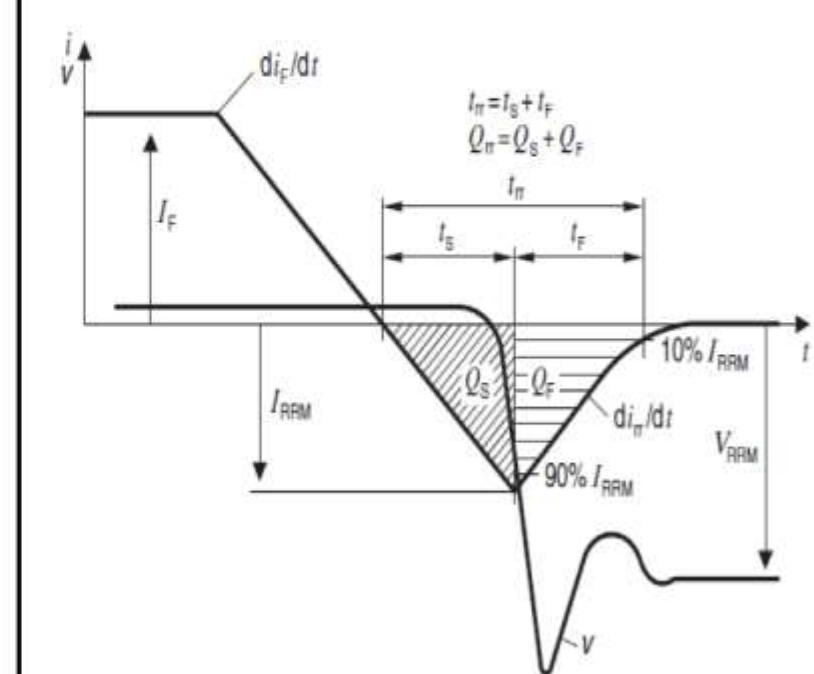


## Test circuit and waveform for diode characteristics

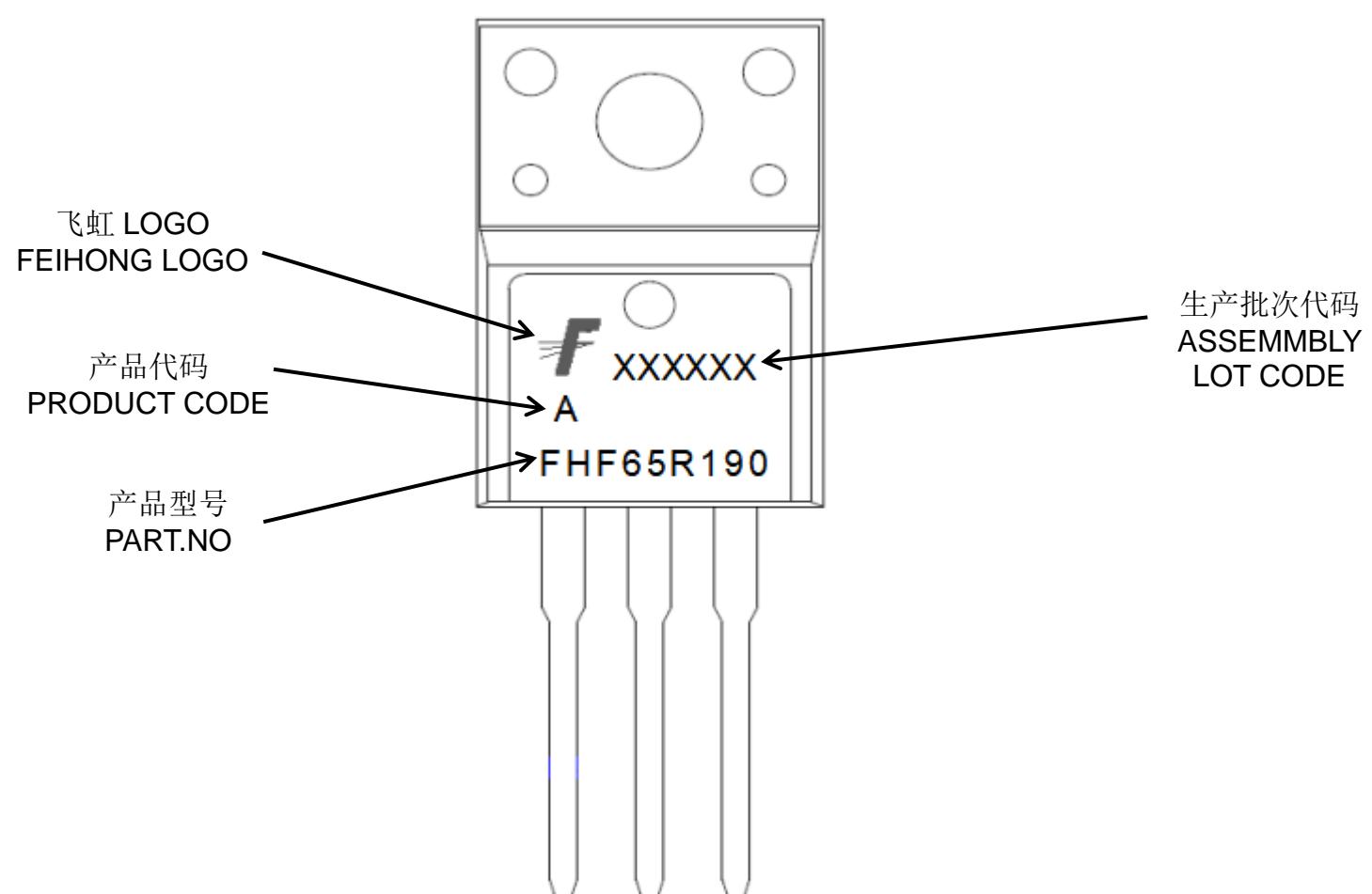
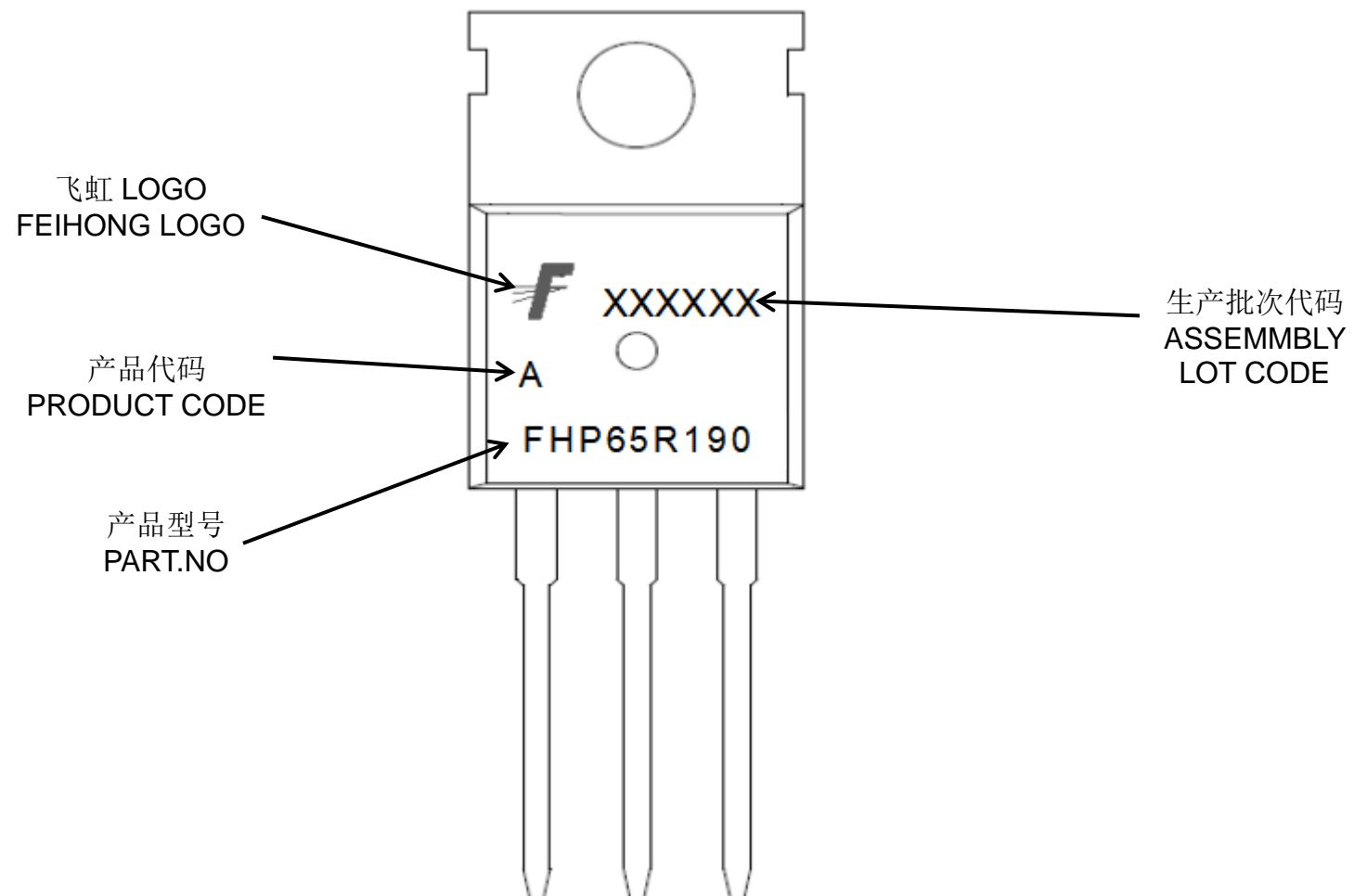
**Test circuit for diode characteristics**

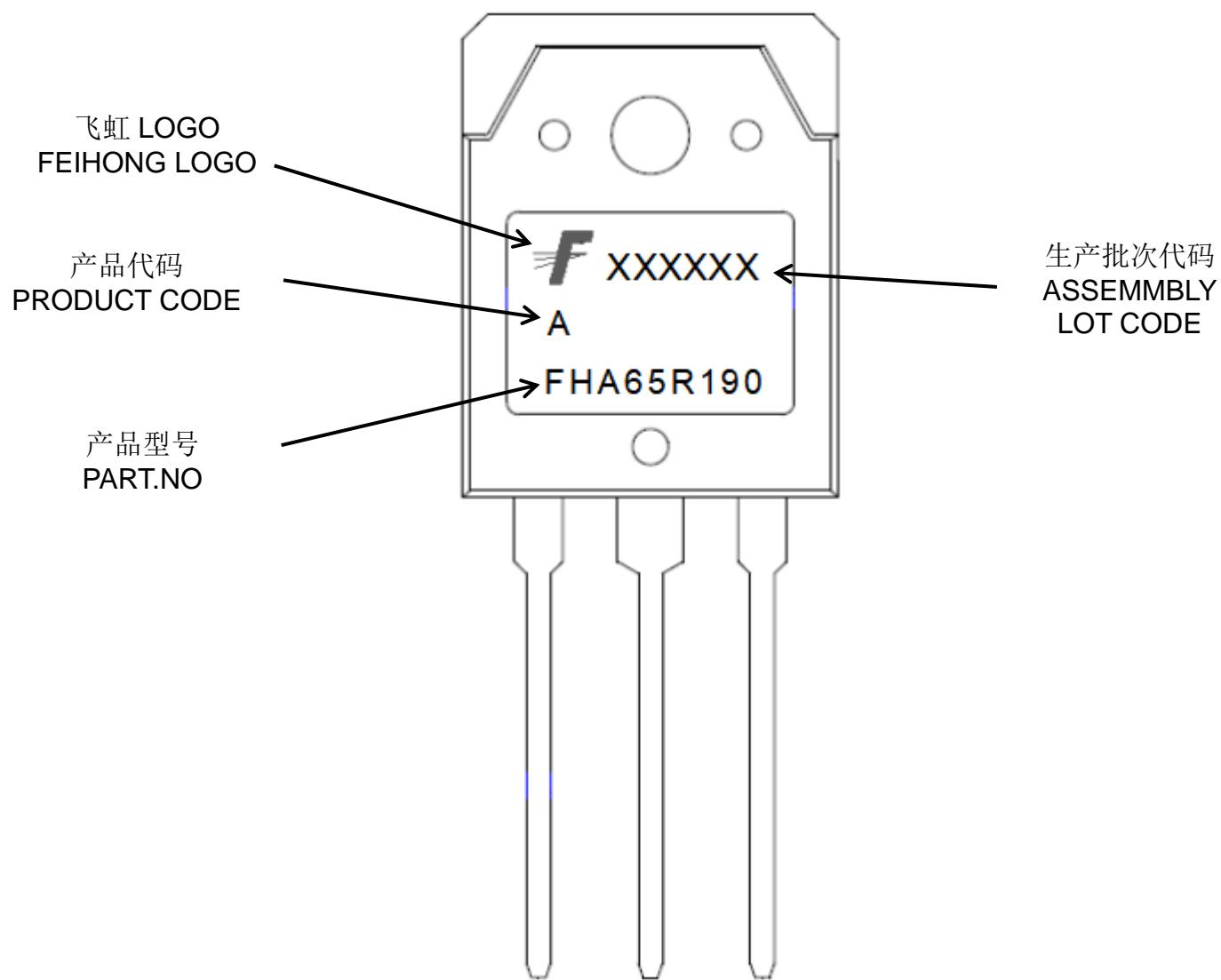


**Diode recovery waveform**



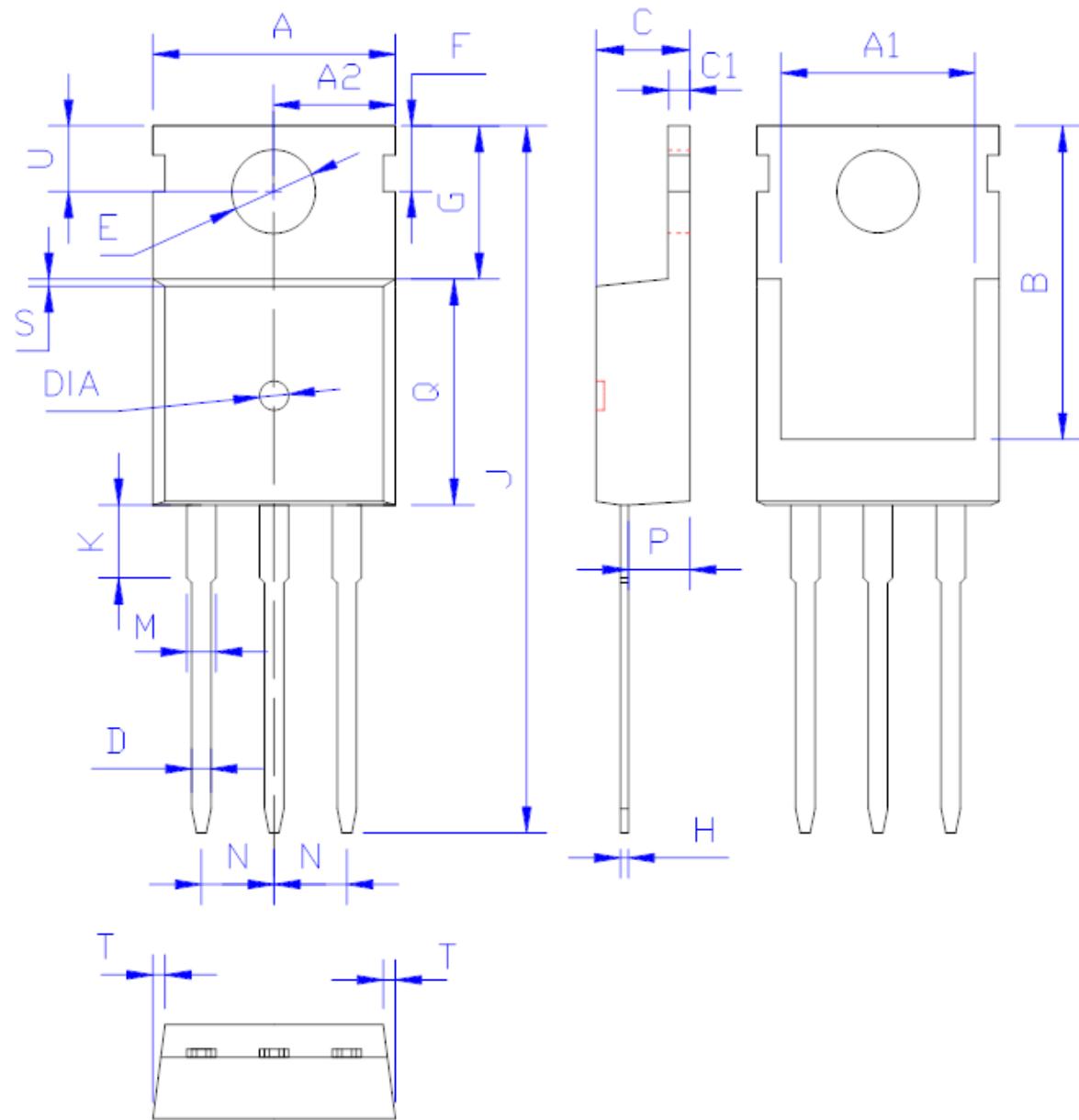
**印记 Marking:**





外形尺寸: Package Dimension:

TO-220



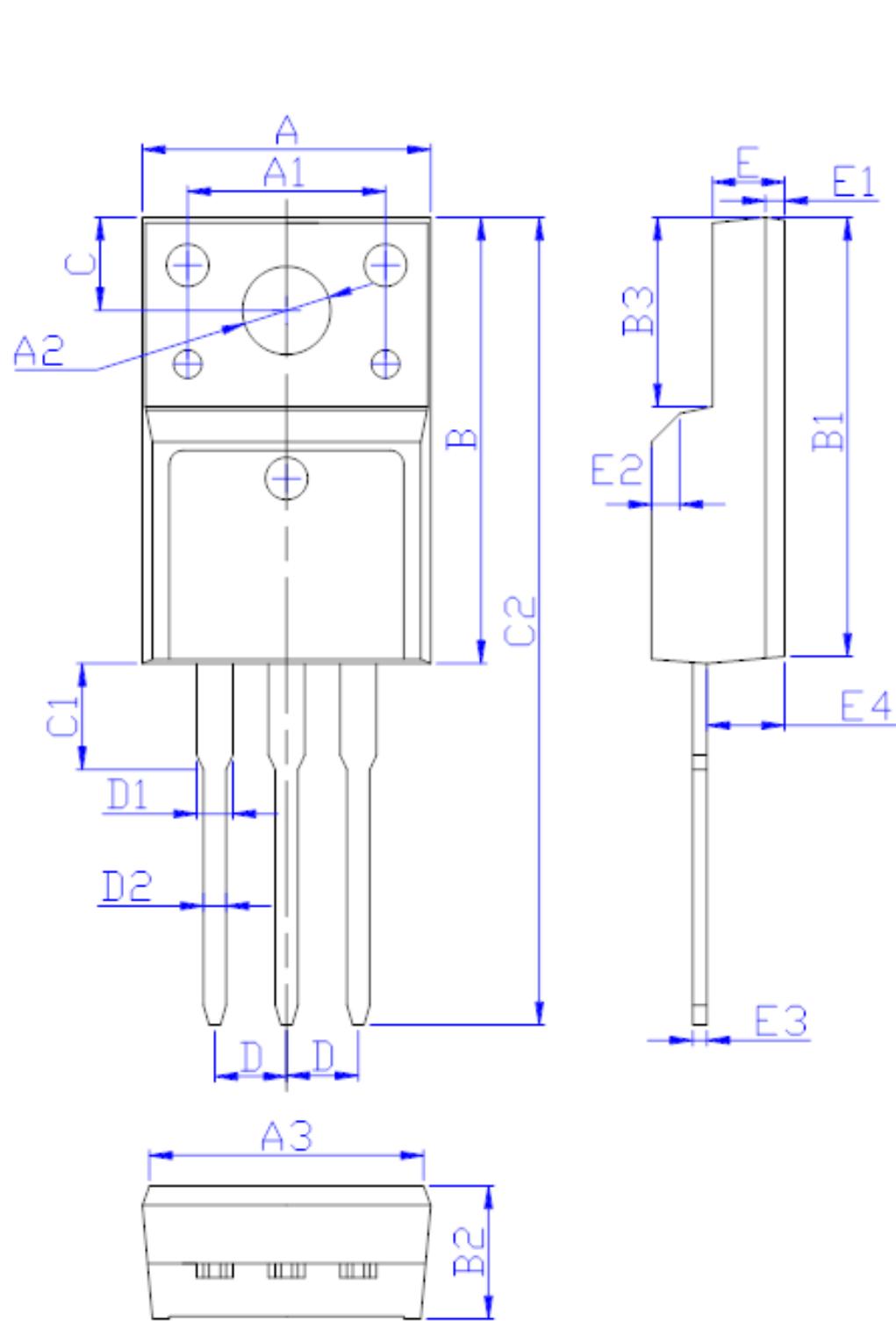
DIM	MILLIMETERS
A	10.00±0.30
A1	8.00±0.30
A2	5.00±0.30
B	13.20±0.40
C	4.50±0.20
C1	1.30±0.20
D	0.80±0.20
E	3.60±0.20
F	3.00±0.30
G	6.60±0.40
H	0.50±0.20
J	28.88±0.50
K	3.00±0.30
M	1.30±0.30
N	Typical 2.54
P	2.40±0.40
Q	9.20±0.40
S	0.25±0.15
T	0.25±0.15
U	2.80±0.30
DIA	寬 1.50±0.10 深 0.50 MAX

(Units: mm)

外形尺寸：

Package Dimension:

TO-220F

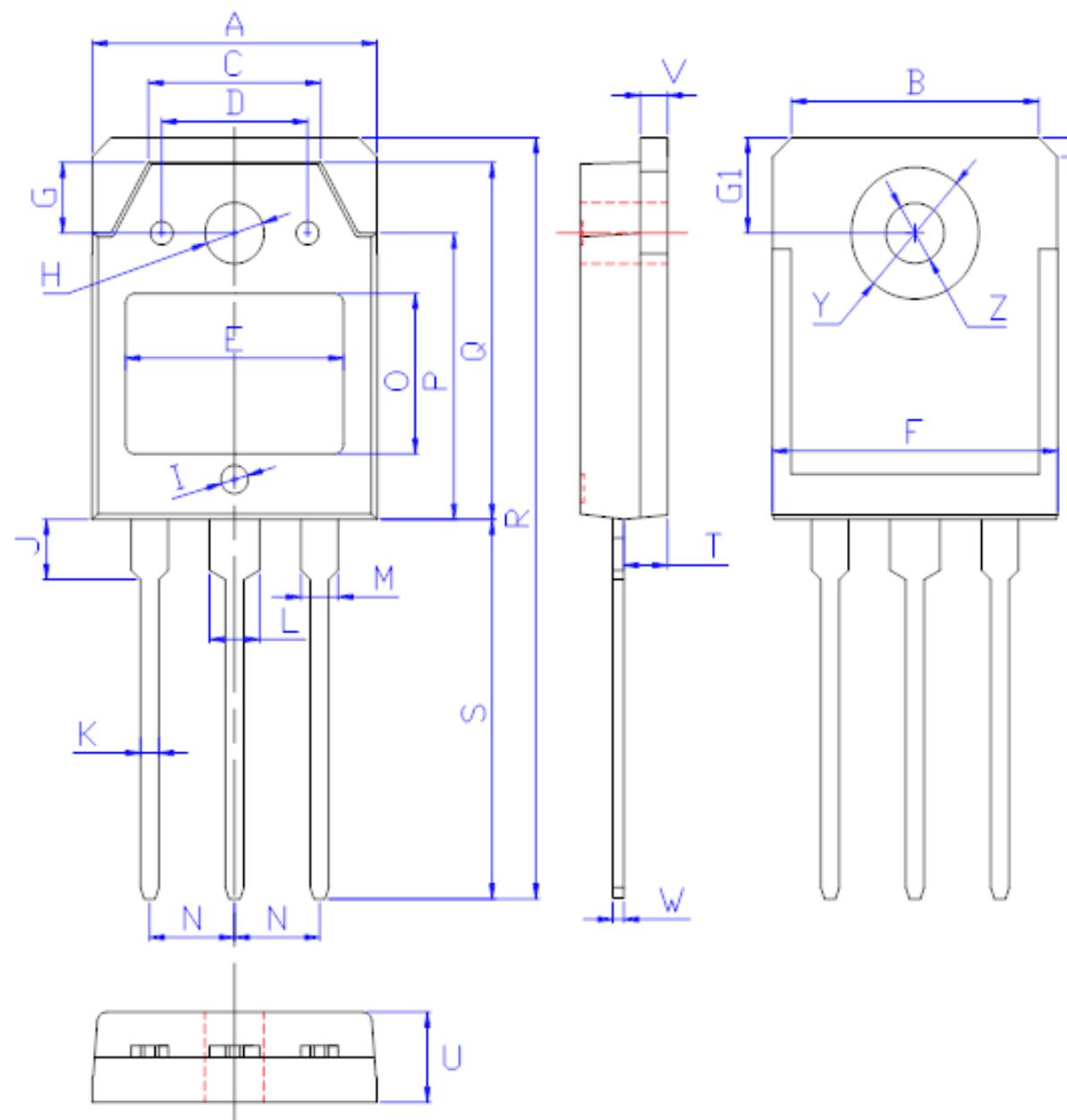


DIM	MILLIMETERS
A	10.16±0.30
A1	7.00±0.20
A2	3.12±0.20
A3	9.70±0.30
B	15.90±0.50
B1	15.60±0.50
B2	4.70±0.30
B3	6.70±0.30
C	3.30±0.25
C1	3.25±0.30
C2	28.70±0.50
D	Typical 2.54
D1	1.47 (MAX)
D2	0.80±0.20
E	2.55±0.25
E1	0.70±0.25
E2	1.0×45°
E3	0.50±0.20
E4	2.75±0.30

(Units: mm)

外形尺寸： Package Dimension:

TO-3PN



DIM	MILLIMETERS
A	15.60±0.30
B	13.60±0.30
C	9.50±0.30
D	8.00±0.30
E	11.85±0.30
F	15.65±0.30
G	3.80±0.30
G1	5.00±0.30
H	Φ3.50±0.30
I	Φ1.50±0.30 深 0.15±0.15
J	3.20±0.30
K	1.00±0.15
L	3.10±0.15
M	2.10±0.15
N	5.45±0.30
O	8.40±0.30
P	13.90±0.30
Q	18.70±0.30
R	40.00±0.60
S	20.00±0.40
T	2.40±0.30
U	4.80±0.30
V	1.50±0.15
W	0.60±0.15
X	1.80±0.40
Y	7.00±0.30
Z	3.20±0.30

(Units: mm)